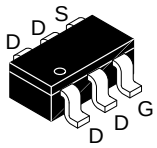
MOSFET – Single, N-Channel, 2.5 V Specified, POWERTRENCH®

20 V, 6.2 A, 24 mΩ

FDC637AN

V_{DSS}	$R_{DS(on)}$ MAX	I_D MAX
20 V	24 mΩ @ 4.5 V	6.2 A
	32 mΩ @ 2.5 V	5.2 A



TSOT23 6−Lead
SUPERSOT−6
CASE 419BL

General Description

This N−Channel 2.5 V specified MOSFET is produced using **onsemi**'s advanced POWERTRENCH process that has been especially tailored to minimize on−state resistance and yet maintain low gate charge for superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint compared with bigger SO−8 and TSSOP−8 packages.

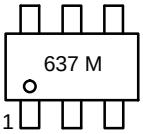
Features

- 6.2 A, 20 V
  - $R_{DS(on)}$ = 0.024 Ω @ V_{GS} = 4.5 V
  - $R_{DS(on)}$ = 0.032 Ω @ V_{GS} = 2.5 V
- Fast Switching Speed
- Low Gate Charge (10.5 nC Typical)
- High Performance Trench Technology for Extremely Low $R_{DS(on)}$
- SUPERSOT™ −6 Package: Small Footprint 72% (Smaller than Standard SO−8); Low Profile (1 mm Thick)
- This Device is Pb−Free, Halide Free and is RoHS Compliant

Applications

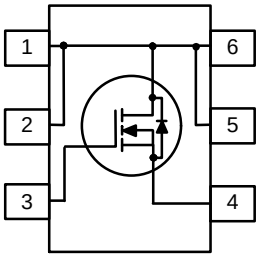
- DC/DC Converter
- Load Switch
- Battery Protection

MARKING DIAGRAM



637 = Specific Device Code
M = Date Code

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain−Source Voltage	20	V
V_{GSS}	Gate−Source Voltage	±8	V
I_D	Drain Current − Continuous (Note 1a) − Pulsed	 6.2 20	A
P_D	Power Dissipation for Single Operation (Note 1a) (Note 1b)	 1.6 0.8	W
T_J, T_{stg}	Operating and Storage Junction Temperature Range	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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THERMAL CHARACTERISTICS (T_A = 25°C, unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$R_{\theta JA}$	Thermal Resistance, Junction−to−Ambient (Note 1a)	78	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction−to−Case (Note 1)	30	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	20	–	–	V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	–	14	–	mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 16 V, V_{GS} = 0 V	–	–	1	μA
I_{GSSF}	Gate–Body Leakage Current, Forward	V_{GS} = 8 V, V_{DS} = 0 V	–	–	100	nA
I_{GSSR}	Gate–Body Leakage Current, Reverse	V_{GS} = –8 V, V_{DS} = 0 V	–	–	−100	nA
ON CHARACTERISTICS (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	0.4	0.82	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 125°C	–	−3	–	mV/°C
$R_{DS(on)}$	Static Drain–Source On–Resistance	V_{GS} = 4.5 V, I_D = 6.2 A V_{GS} = 4.5 V, I_D = 6.2 A, T_J = 125°C V_{GS} = 2.5 V, I_D = 5.2 A	– – –	0.019 0.028 0.025	0.024 0.041 0.032	Ω
$I_{D(on)}$	On–State Drain Current	V_{GS} = 4.5 V, V_{DS} = 5 V	10	–	–	A
g_{FS}	Forward Transconductance	V_{DS} = 5 V, I_D = 6.2 A	–	7.4	–	S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input Capacitance	V_{DS} = 10 V, V_{GS} = 0 V, f = 1.0 MHz	–	1125	–	pF
C_{oss}	Output Capacitance		–	290	–	pF
C_{rss}	Reverse Transfer Capacitance		–	145	–	pF
SWITCHING CHARACTERISTICS (Note 2)						
$t_{d(on)}$	Turn–On Delay Time	V_{DD} = 10 V, I_D = 1 A, V_{GS} = 4.5 V, R_{GEN} = 6 Ω	–	9	18	ns
t_r	Turn–On Rise Time		–	13	24	ns
$t_{d(off)}$	Turn–Off Delay Time		–	26	42	ns
t_f	Turn–Off Fall Time		–	11	20	ns
Q_g	Total Gate Charge	V_{DS} = 5 V, I_D = 6.2 A, V_{GS} = 4.5 V	–	10.5	16	nC
Q_{gs}	Gate–Source Charge		–	1.5	–	nC
Q_{gd}	Gate–Drain Charge		–	2.2	–	nC
DRAIN–SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
I_S	Maximum Continuous Drain–Source Diode Forward Current		–	–	1.3	A
V_{SD}	Drain–Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 1.3 A (Note 2)	–	0.7	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. $R_{\theta JA}$ is the sum of the junction−to−case and case−to−ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.
   a. 78°C/W when mounted on a 1.0 in^2 pad of 2 oz. copper.
   b. 156°C/W when mounted on a minimum pad of 2 oz. copper.
2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

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TYPICAL CHARACTERISTICS

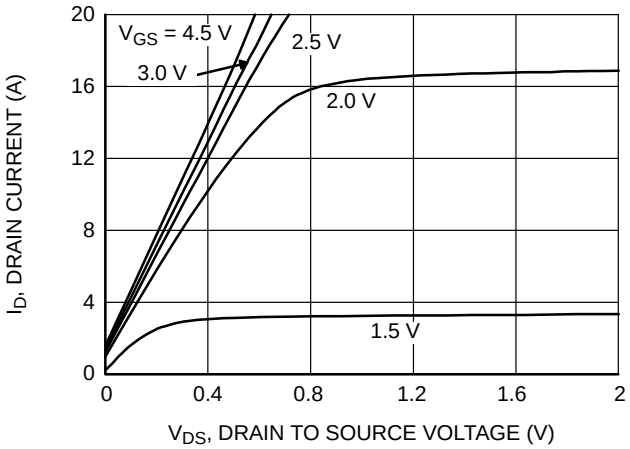


Figure 1. On−Region Characteristics

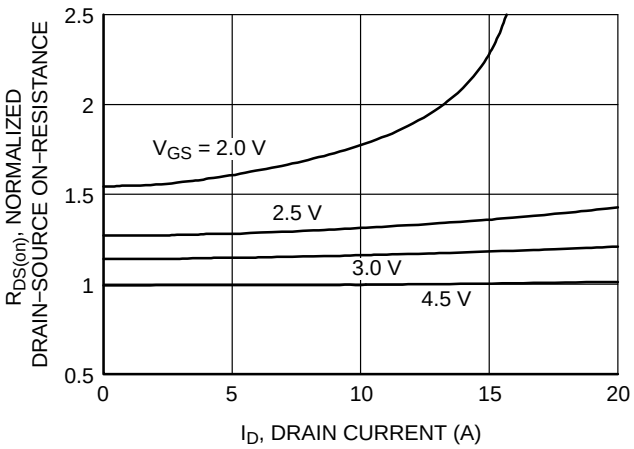


Figure 2. On−Resistance Variation with Drain Current and Gate Voltage

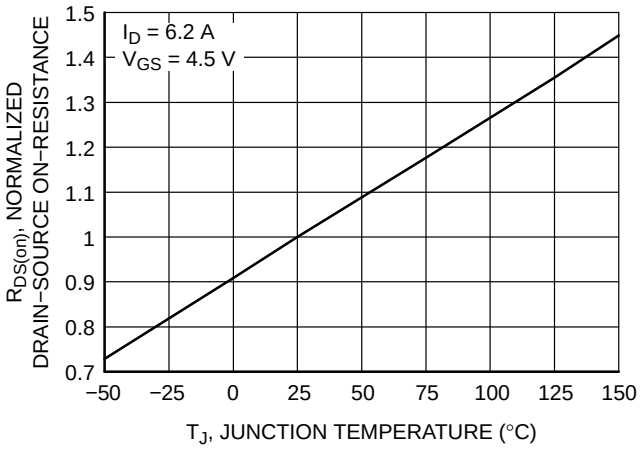


Figure 3. On−Resistance Variation with Temperature

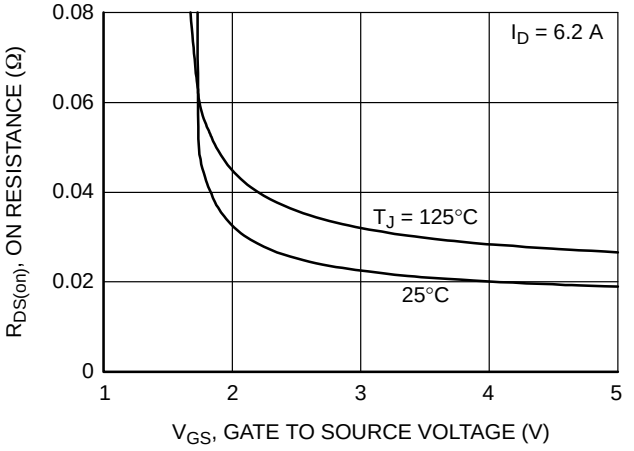


Figure 4. On−Resistance Variation with Gate−to−Source Voltage

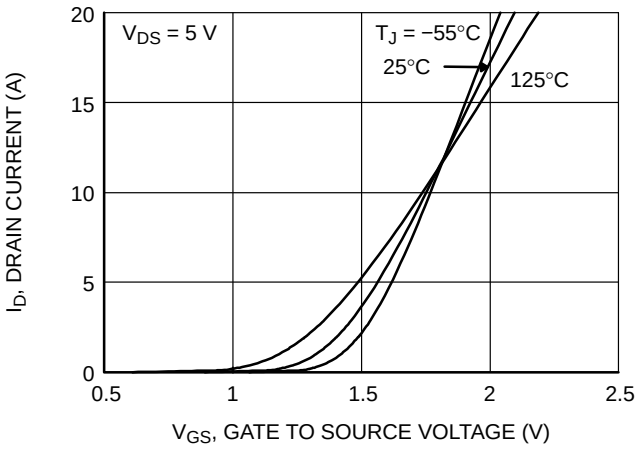


Figure 5. Transfer Characteristics

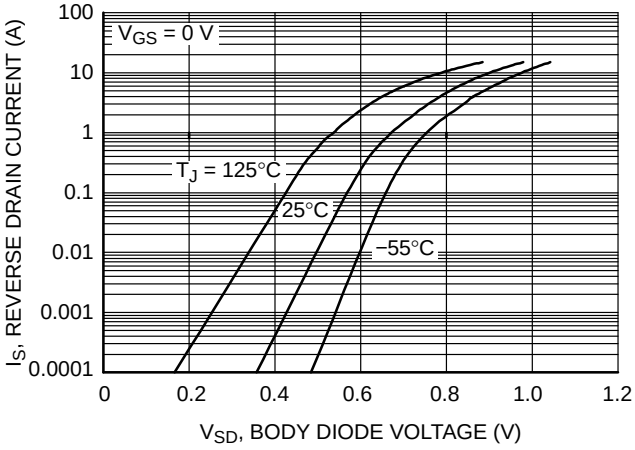


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

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TYPICAL CHARACTERISTICS (continued)

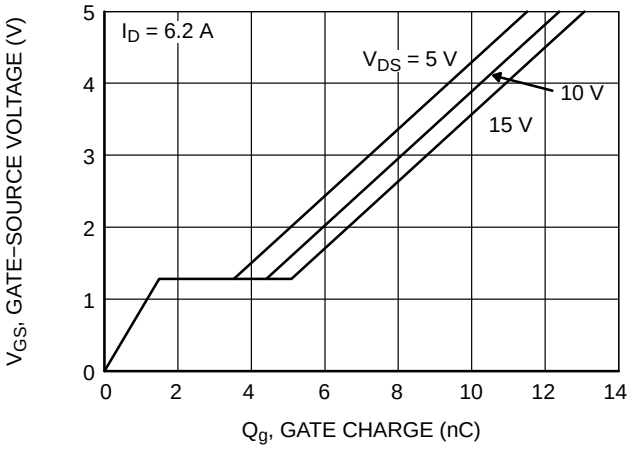


Figure 7. Gate−Charge Characteristics

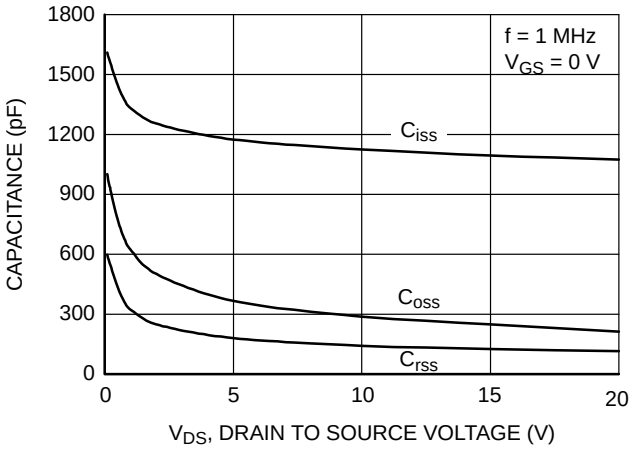


Figure 8. Capacitance Characteristics

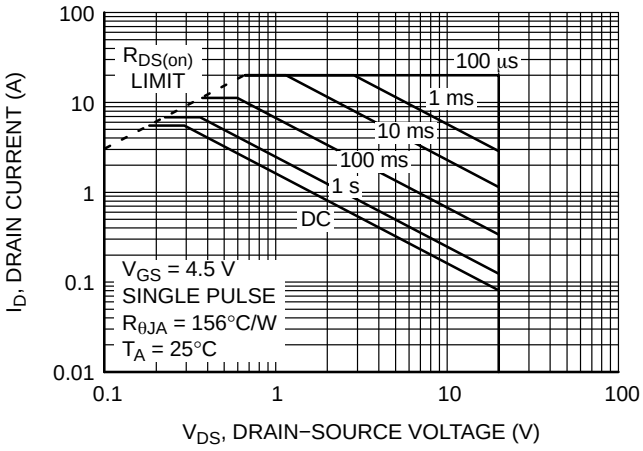


Figure 9. Maximum Safe Operating Area

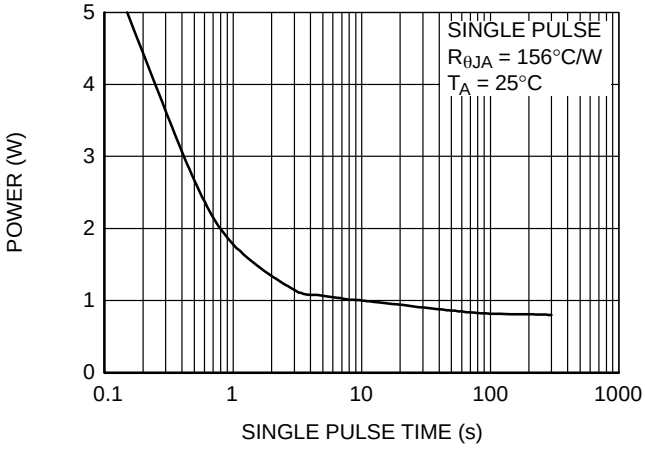


Figure 10. Single Pulse Maximum Power Dissipation

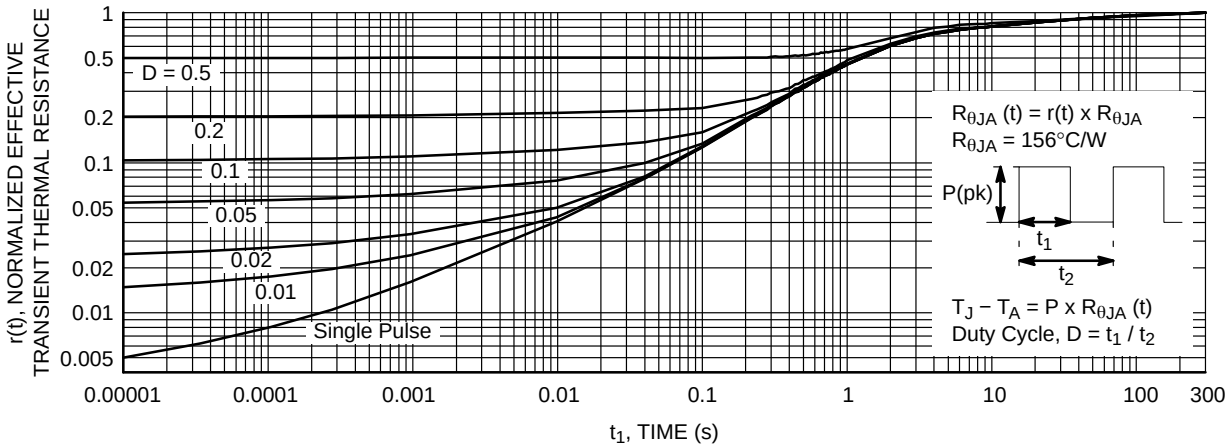


Figure 11. Transient Thermal Response Curve

(Thermal characterization performed using the conditions described in Note 1b.
Transient thermal response will change depending on the circuit board design.)

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PACKAGE OUTLINES AND ORDERING INFORMATION

Device	Device Marking	Package	Reel Size	Tape Width	Shipping†
FDC637AN	637	TSOT23 6−Lead SUPERSOT−6 (Pb−Free, Halide Free)	7”	8 mm	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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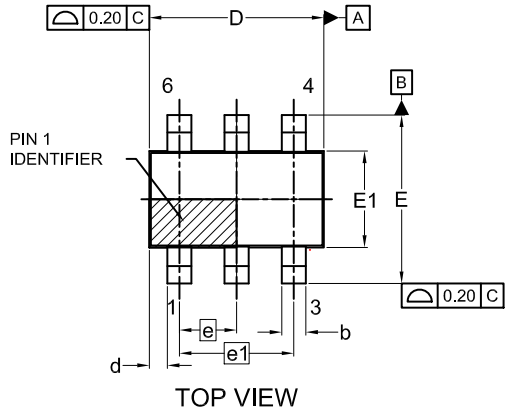
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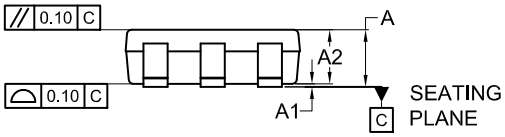
1
SCALE 2:1

TSOT23 6−Lead
CASE 419BL
ISSUE A

DATE 31 AUG 2020

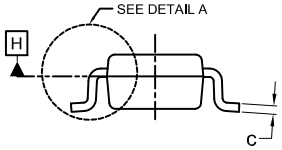


TOP VIEW

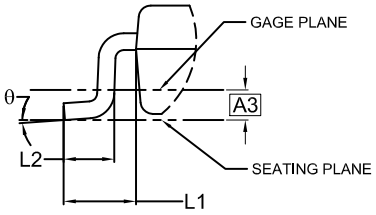


FRONT VIEW

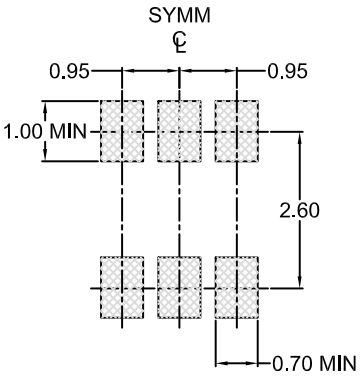
NOTE 4



SIDE VIEW



DETAIL A



LAND PATTERN
RECOMMENDATION

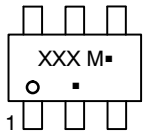
*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.25MM PER END. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
4. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.00	0.05	0.10
A2	0.70	0.85	1.00
A3		0.25 BSC	
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.80	2.95	3.10
d		0.30 REF	
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e		0.95 BSC	
e1		1.90 BSC	
L1		0.60 REF	
L2	0.20	0.40	0.60
θ	0°	---	10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**TSOT23 6−Lead**	**PAGE 1 OF 1**

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

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